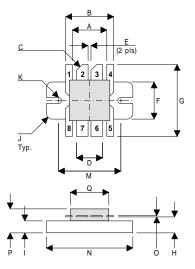
TetraFET

D1034UK



ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA



DD

SOURCE (COMMON) PIN 2 PIN 1 DRAIN 1 PIN 3 DRAIN 2 SOURCE (COMMON) PIN 4 PIN 5 SOURCE (COMMON) PIN 6 GATE 2

PIN 7

GATE 1

PIN 8 SOURCE (COMMON)

			- (-
mm	Tol.	Inches	Tol.
9.14	0.13	0.360	0.005
12.70	0.13	0.500	0.005
45°	5°	45°	5°
6.86	0.13	0.270	0.005
0.76	0.13	0.030	0.005
9.78	0.13	0.385	0.005
19.05	0.25	0.750	0.010
4.19	0.13	0.165	0.005
3.17	0.13	0.125	0.005
1.52R	0.13	0.060R	0.005
1.65R	0.13	0.065R	0.005
16.51	0.13	0.650	0.005
22.86	0.13	0.900	0.005
0.13	0.02	0.005	0.001
6.35	0.64	0.250	0.025
10.77	0.13	0.424	0.005
	9.14 12.70 45° 6.86 0.76 9.78 19.05 4.19 3.17 1.52R 1.65R 16.51 22.86 0.13 6.35	$\begin{array}{c ccccc} 9.14 & 0.13 \\ 12.70 & 0.13 \\ 45^{\circ} & 5^{\circ} \\ 6.86 & 0.13 \\ 0.76 & 0.13 \\ 9.78 & 0.13 \\ 19.05 & 0.25 \\ 4.19 & 0.13 \\ 3.17 & 0.13 \\ 1.52R & 0.13 \\ 1.65R & 0.13 \\ 16.51 & 0.13 \\ 22.86 & 0.13 \\ 0.13 & 0.02 \\ 6.35 & 0.64 \\ \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

GOLD METALLISED **MULTI-PURPOSE SILICON DMOS RF FET** 80W - 28V - 400MHz **PUSH-PULL**

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 13 dB MINIMUM

APPLICATIONS

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 500 MHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

P _D	Power Dissipation	175W
BV _{DSS}	Drain – Source Breakdown Voltage *	70V
BV _{GSS}	Gate – Source Breakdown Voltage *	±20V
I _{D(sat)}	Drain Current *	10A
T _{stg}	Storage Temperature	–65 to 150°C
Тj	Maximum Operating Junction Temperature	200°C

Per Side

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.



ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test	Min.	Тур.	Max.	Unit		
	PER SIDE							
BV	Drain–Source	$V_{GS} = 0$	$l_{-} = 100 m \Lambda$	70			V	
BV _{DSS}	Breakdown Voltage	$V_{GS} = 0$ $I_D = 100 \text{mA}$		70			v	
	Zero Gate Voltage	<u> </u>				2		
IDSS	Drain Current	$V_{DS} = 28V$	$V_{GS} = 0$			Z	mA	
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	$V_{DS} = 0$			1	μA	
V _{GS(th)}	Gate Threshold Voltage *	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V	
9 _{fs}	Forward Transconductance *	V _{DS} = 10V	I _D = 2A	1.6			S	
	TOTAL DEVICE							
G _{PS}	Common Source Power Gain	P _O = 80W		13			dB	
η	Drain Efficiency	V _{DS} = 28V	I _{DQ} = 0.8A	50			%	
VSWR	Load Mismatch Tolerance	f = 500MHz		20:1			_	
PER SIDE								
C _{iss}	Input Capacitance	V _{DS} = 28V \	$V_{GS} = -5V f = 1MHz$			120	pF	
C _{oss}	Output Capacitance	V _{DS} = 28V	$I_{GS} = 0$ f = 1MHz			60	pF	
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 28V	$I_{GS} = 0$ f = 1MHz			5	pF	

* Pulse Test: Pulse Duration = 300 μs , Duty Cycle $\leq 2\%$

HAZARDOUS MATERIAL WARNING

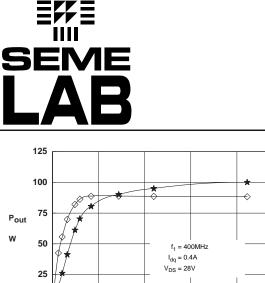
The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 1°C / W
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80 60 Drain Efficiency % w 40 20 0 4 8 12 16 20 Pout P_{in} W

Drain Efficiency

100



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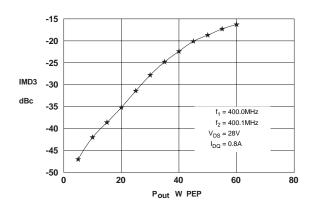


Figure 3 – IMD vs. Output Power.

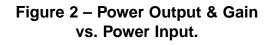


- Vds=28V, Idq=1A !
- S MA R 50 # MHz

!Freq	S11		S21		S12		S22	
MHz	mag	ang	mag	ang	mag	ang	mag	ang
100	0.794	-158	14.622	69	0.0115	-7	0.61	-145
200	0.881	-167	5.821	42	0.0061	3	0.794	-156
300	0.923	-171	3.02	28	0.0068	60	0.871	-162
400	0.923	-176	1.82	18	0.117	77	0.902	-167
500	0.937	-179	1.439	15	0.0168	76	0.923	-169
600	0.952	177	1.057	13	0.0234	75	0.945	-171
700	0.966	174	0.676	10	0.0285	74	0.966	-174
800	0.966	171	0.543	5	0.0335	69	0.955	-177
900	0.977	167	0.447	1	0.0394	64	0.966	178
1000	0.966	165	0.359	1	0.0432	64	0.955	178

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125 17 100 15 ĊŚ) f₁ = 400.0MHz 75 $I_{dq} = 0.4A$ 13 Pout Gain V_{DS} = 28V dB 11 50 25 9 \diamond 0. 7 ñ 4 8 12 16 20 - Pout - Gain Pin W ÷



D1034UK **OPTIMUM SOURCE AND LOAD IMPEDANCE**

Frequency	Z _S	ZL
MHz	Ω	Ω
400	1.5 + j0.2	5.0 + j2.0

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Website: http://www.semelab.co.uk

D1034UK



D1034UK

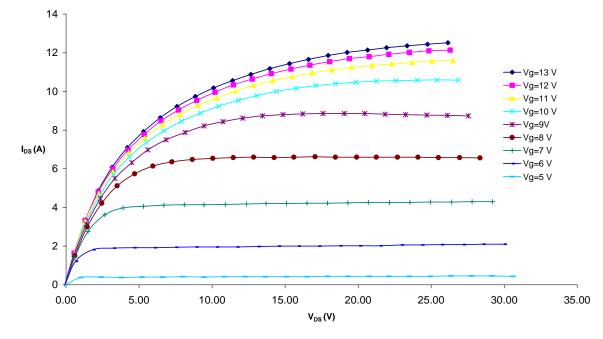
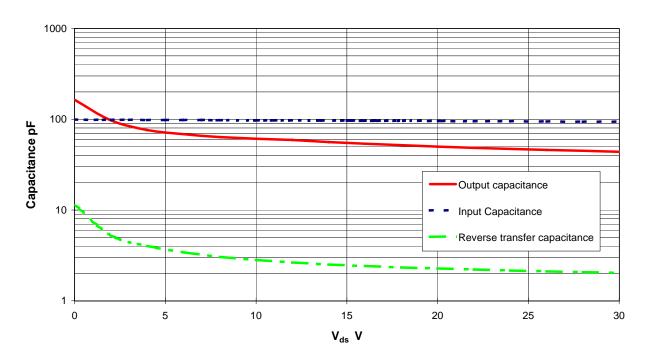


Figure 4 – Typical IV Characteristics.

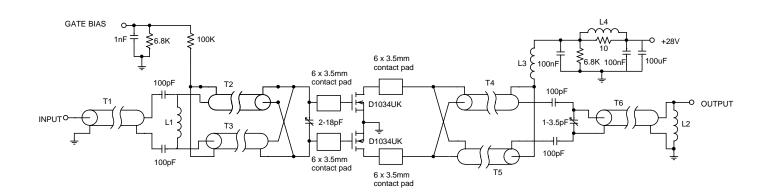




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D1034UK



D1034UK TEST FIXTURE

Substrate 1.6mm PTFE/glass, Er=2.5 All microstrip lines W=4.4mm

- T6 70mm 50 Ω UT85 SEMI RIGID COAX
- L1 3.5 turns of 24swg ECW, 3mm ID
- L2 5.5 turns of 24swg ECW, 4mm ID
- L3 4 turns of 21swg ECW, 7mm ID
- L4 3 turns of 21swg ECW on Fair-Rite FT50-75 core

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